

Transistor

4V Drive Nch MOSFET

RRS110N03

●Structure

Silicon N-channel MOSFET

●Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (SOP8).

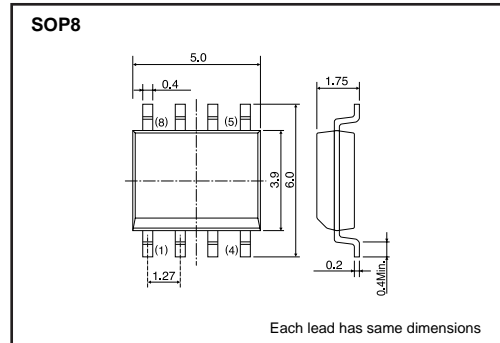
●Applications

Switching

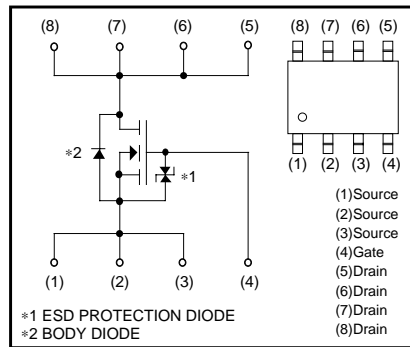
●Packaging specifications

Type	Package	Taping
	Code	TB
	Basic ordering unit (pieces)	2500
RRS110N03		○

●Dimensions (Unit : mm)



●Equivalent circuit



*A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use the protection circuit when the fixed voltages are exceeded.

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V _{DSS}	30	V	
Gate-source voltage	V _{GSS}	±20	V	
Drain current	Continuous	I _D	±11	A
	Pulsed	I _{DP} *1	±44	A
Source current (Body diode)	Continuous	I _S	1.6	A
	Pulsed	I _{SP} *1	44	A
Total power dissipation	P _D *2	2.0	W	
Channel temperature	T _{ch}	150	°C	
Range of storage temperature	T _{stg}	-55 to +150	°C	

*1 Pw≤10μs, Duty cycle≤1%
*2 Mounted on a ceramic board.

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	R _{th (ch-a)} *	62.5	°C / W

* Mounted on a ceramic board.

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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	–	–	±10	μA	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR) DSS}$	30	–	–	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	–	–	1	μA	$V_{DS}=30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	1.0	–	2.5	V	$V_{DS}=10V, I_D=1mA$
Static drain-source on-start resistance	$R_{DS(on)}$ *	–	9.0	12.6	mΩ	$I_D=11A, V_{GS}=10V$
		–	11.0	15.4		$I_D=11A, V_{GS}=4.5V$
		–	11.5	16.0		$I_D=11A, V_{GS}=4V$
Forward transfer admittance	$ Y_{fs} $ *	10	–	–	S	$I_D=11A, V_{DS}=10V$
Input capacitance	C_{iss}	–	2000	–	pF	$V_{DS}=10V$
Output capacitance	C_{oss}	–	330	–	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	–	280	–	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}$ *	–	16	–	ns	$I_D=5.5A, V_{DD}\doteq 15V$
Rise time	t_r *	–	60	–	ns	$V_{GS}=10V$
Turn-off delay time	$t_{d(off)}$ *	–	80	–	ns	$R_L=2.73\Omega$
Fall time	t_f *	–	100	–	ns	$R_G=10\Omega$
Total gate charge	Q_g *	–	22.0	33.0	nC	$I_D=11A, V_{DD}\doteq 15V$
Gate-source charge	Q_{gs} *	–	5.5	–	nC	$V_{GS}=5V$
Gate-drain charge	Q_{gd} *	–	7.5	–	nC	$R_L=1.36\Omega, R_G=10\Omega$

*Pulsed

●Body diode characteristics (Source-Drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD} *	–	–	1.2	V	$I_S=11A, V_{GS}=0V$

*Pulsed

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●Electrical characteristic curves

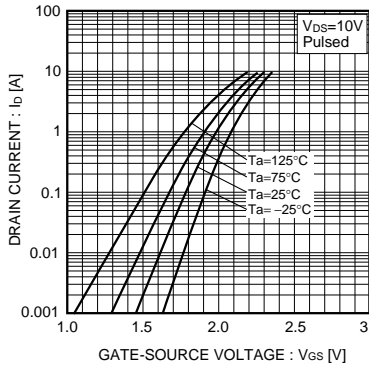


Fig.1 Typical Transfer Characteristics

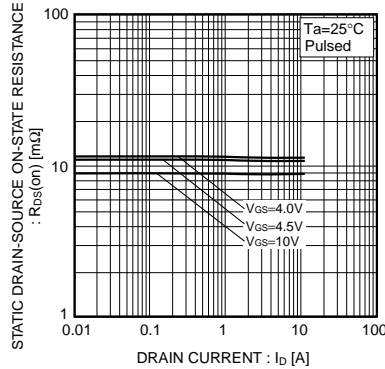


Fig.2 Static Drain-Source On-State Resistance vs. Drain Current(I)

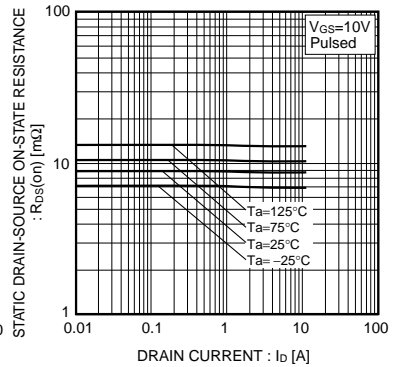


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current(II)

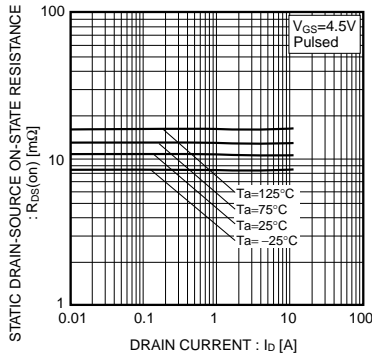


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(III)

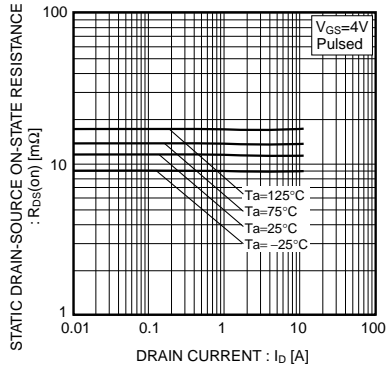


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(IV)

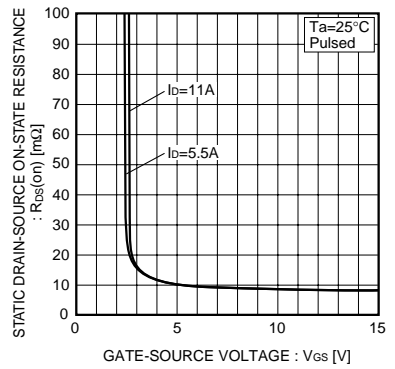


Fig.6 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

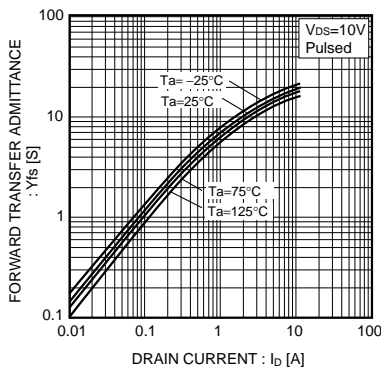


Fig.7 Forward Transfer Admittance vs. Drain Current

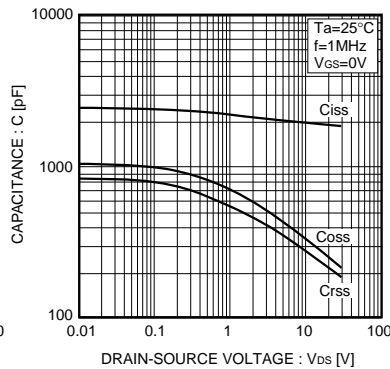


Fig.8 Typical Capacitance vs. Drain-Source Voltage

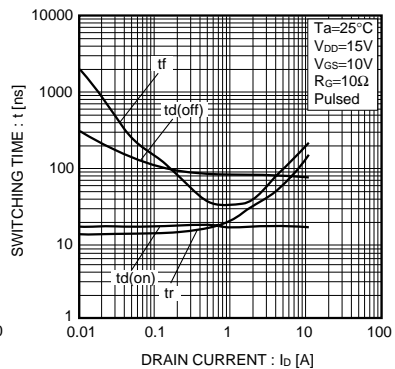


Fig.9 Switching Characteristics

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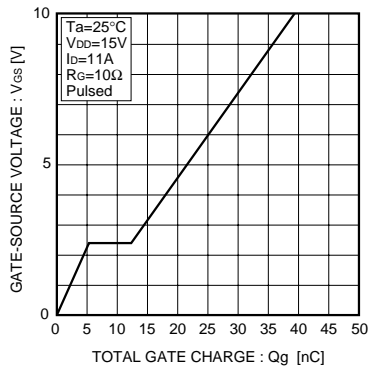


Fig.10 Dynamic Input Characteristics

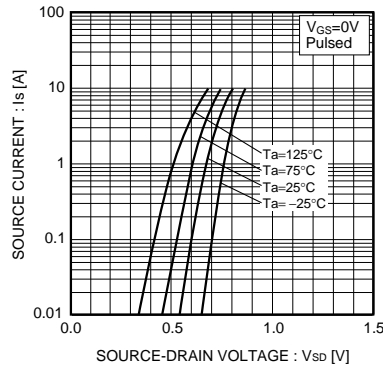


Fig.11 Source Current vs. Source-Drain Voltage

●Measurement circuit

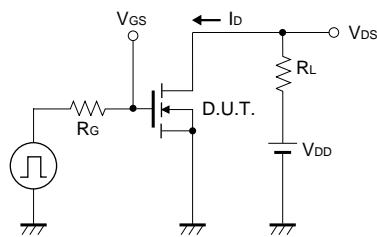


Fig.12 Switching Time Test Circuit

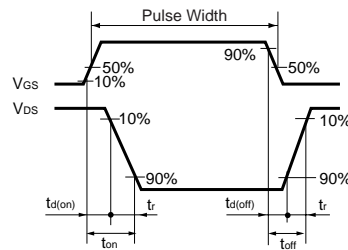


Fig.13 Switching Time Waveforms

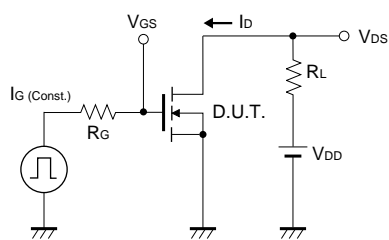


Fig.14 Gate Charge Test Circuit

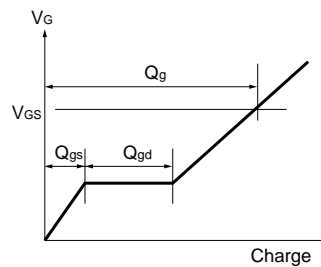


Fig.15 Gate Charge Waveform

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